# SEMICONDUCTOR TECHNICAL DATA

# **FTK2341E**

#### **DESCRIPTION**

The FTK2341E uses advanced trench technology to provide excellent  $R_{\text{DS(ON)}}$ , low gate charge and operation with gate voltages as low as -2.5V.

### **GENERAL FEATURES**

•  $V_{DS} = -20V, I_{D} = -4A$ 

 $R_{DS(ON)} < 73m\Omega$  @  $V_{GS}$ =-1.8V

 $R_{DS(ON)} < 54m\Omega$  @  $V_{GS}$ =-2.5V

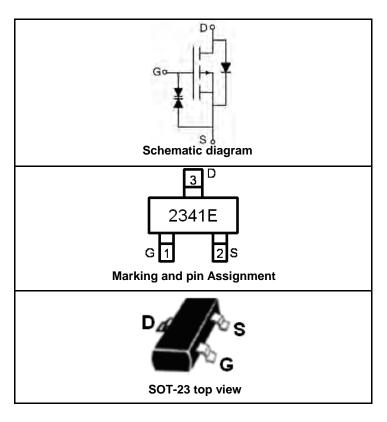
 $R_{DS(ON)} < 43m\Omega$  @  $V_{GS}$ =-4.5V

ESD Rating: 3000V HBM

- High Power and current handing capability
- Lead free product is acquired
- Surface Mount Package

## **Application**

- Battery protection
- Load switch
- Power management



#### PACKAGE MARKING AND ORDERING INFORMATION

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
2341E	FTK2341E	SOT-23	Ø330mm	12mm	3000 units

ABSOLUTE MAXIMUM RATINGS(TA=25℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V <sub>DS</sub>	-20	V	
Gate-Source Voltage	V <sub>G</sub> s	±8	V	
Dunin Compant Continuous @ Compant Dulond (Nate 4)	I <sub>D</sub>	-4	Α	
Drain Current-Continuous@ Current-Pulsed (Note 1)	I <sub>DM</sub>	-30	А	
Maximum Power Dissipation	P <sub>D</sub>	1.4	W	
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 150	$^{\circ}$	

#### THERMAL CHARACTERISTICS

Thermal Resistance, Junction-to-Ambient (Note 2)	R <sub>0JA</sub>	90	°C/W	I
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**ELECTRICAL CHARACTERISTICS (TA=25°C unless otherwise noted)** 

Parameter	Symbol	Condition	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =-250µA	-20			V



# FTK2341E

Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-16V,V <sub>GS</sub> =0V			-1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}=\pm 8V, V_{DS}=0V$			±10	uA
ON CHARACTERISTICS (Note 3)		•	•			
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =-250μA	-0.3	-0.55	-1	V
		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-4A		37	43	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-4A		45	54	mΩ
		V <sub>GS</sub> =-1.8V, I <sub>D</sub> =-2A		56	73	mΩ
Forward Transconductance	g <sub>FS</sub>	V <sub>DS</sub> =-5V,I <sub>D</sub> =-4A	4	8		S
DYNAMIC CHARACTERISTICS (Note4)						
Input Capacitance	C <sub>lss</sub>			1450		PF
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ =-10V, $V_{GS}$ =0V, F=1.0MHz		200		PF
Reverse Transfer Capacitance	C <sub>rss</sub>			160		PF
SWITCHING CHARACTERISTICS (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>			9.5		nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =-10V, $I_{D}$ =-1A		17		nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =-4.5V, $R_{GEN}$ =3 $\Omega$		90		nS
Turn-Off Fall Time	t <sub>f</sub>			30		nS
Total Gate Charge	$Q_g$			17		nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =-10V, $I_{D}$ =-4A, $V_{GS}$ =-4.5V		1.3		nC
Gate-Drain Charge	$Q_{gd}$	- 165		4.5		nC
DRAIN-SOURCE DIODE CHARACTERISTICS	•	•	•	•		
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =-1A		-0.76	-1	V

## **NOTES:**

Repetitive Rating: Pulse width limited by maximum junction temperature.
 Surface Mounted on 1in² FR4 Board, t ≤ 10 sec.
 Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
 Guaranteed by design, not subject to production testing.

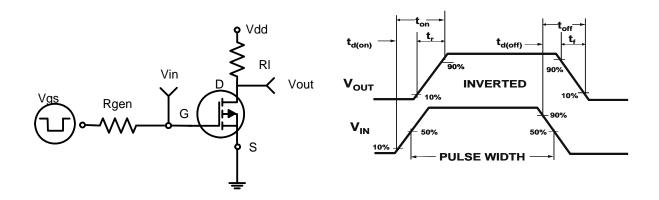
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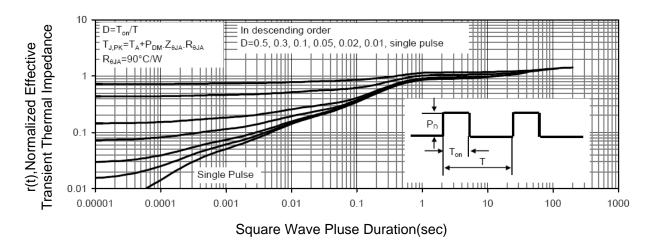
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# **FTK2341E**

## TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS





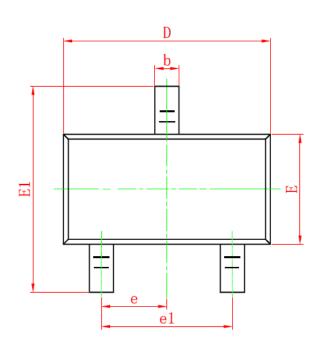
**Figure 3 Normalized Maximum Transient Thermal Impedance** 

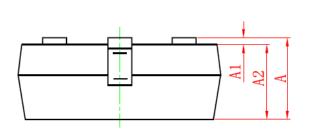
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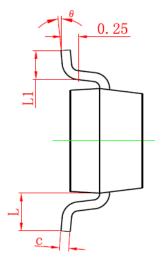


# **SOT-23 PACKAGE INFORMATION**

## **Dimensions in Millimeters (UNIT:mm)**







Cumbal	Dimensions in Millimeters			
Symbol	MIN.	MAX.		
Α	0.900	1.150		
A1	0.000	0.100		
A2	0.900	1.050		
b	0.300	0.500		
С	0.080	0.150		
D	2.800	3.000		
Е	1.200	1.400		
E1	2.250	2.550		
е	0.950	0.950TYP		
e1	1.800	2.000		
L	0.550REF			
L1	0.300	0.500		
θ	0°	8°		

### **NOTES**

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
  3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.